

## Dual Trench MOS Barrier Schottky Rectifier

 Ultra Low  $V_F = 0.52 \text{ V}$  at  $I_F = 5 \text{ A}$ 


### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 10 A
$V_{RRM}$	80 V
$I_{FSM}$	100 A
$V_F$ at $I_F = 10 \text{ A}$	0.60 V
$T_J \text{ max.}$	150 °C
Package	ITO-220AB
Diode variation	Dual Common Cathode

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating  
 Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	VFT2080C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	80	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	20
		per diode	10
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	100	A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000	V/ $\mu$ s
Isolation voltage from terminal to heatsink $t = 1 \text{ min}$	$V_{AC}$	1500	V
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150	°C

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS	SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.57	-	V
	$I_F = 10\text{ A}$			0.67	0.81	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.52	-	
	$I_F = 10\text{ A}$			0.60	0.70	
Reverse current per diode	$V_R = 80\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	20	600	$\mu\text{A}$
		$T_A = 125\text{ }^\circ\text{C}$		10	20	mA

**Notes**

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle  
 (2) Pulse test: Pulse width  $\leq 40\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VFT2080C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	6.0	$^\circ\text{C/W}$
	per device		5.0	

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VFT2080C-M3/4W	1.73	4W	50/tube	Tube

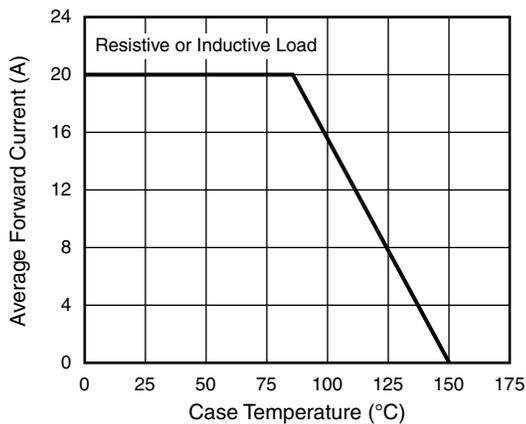
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)


Fig. 1 - Maximum Forward Current Derating Curve

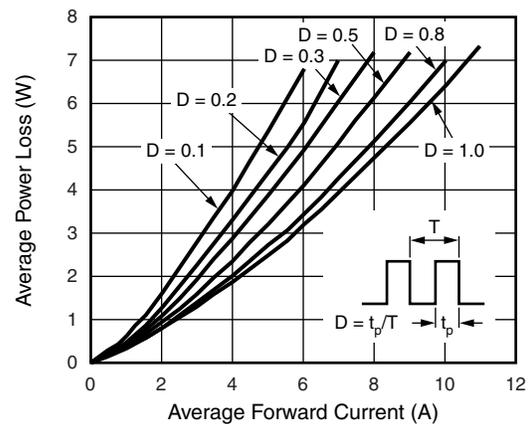


Fig. 2 - Forward Power Dissipation Characteristics

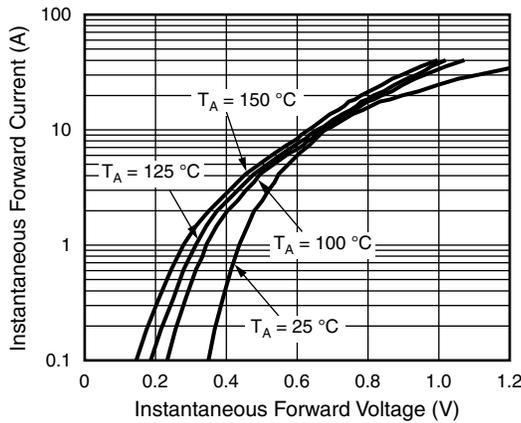


Fig. 3 - Typical Instantaneous Forward Characteristics

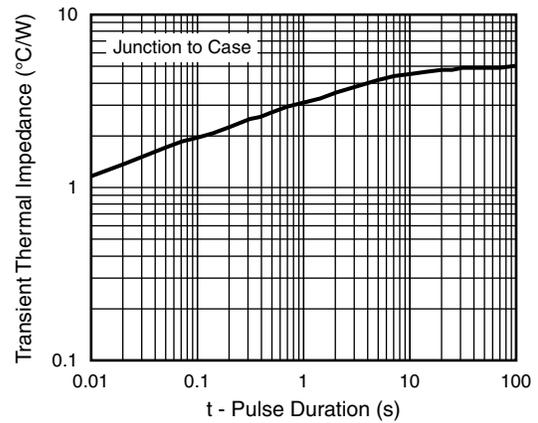


Fig. 5 - Typical Transient Thermal Impedance

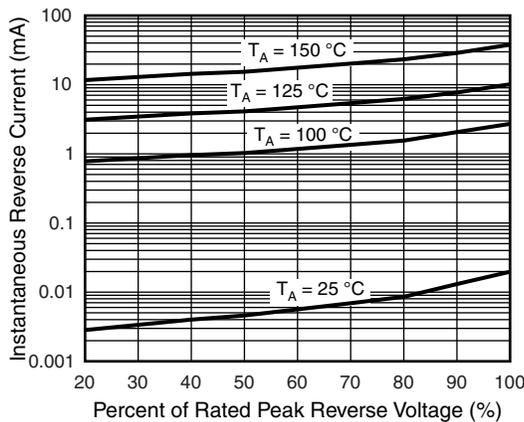


Fig. 4 - Typical Reverse Characteristics

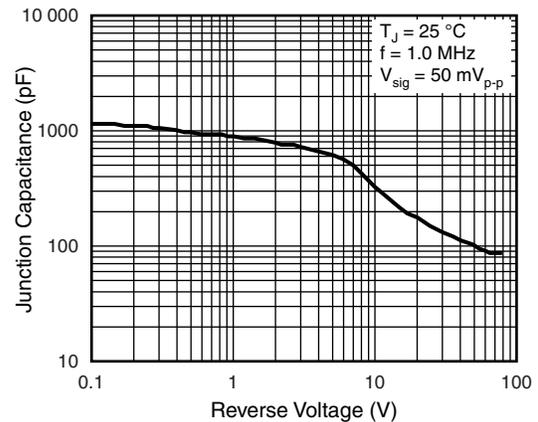
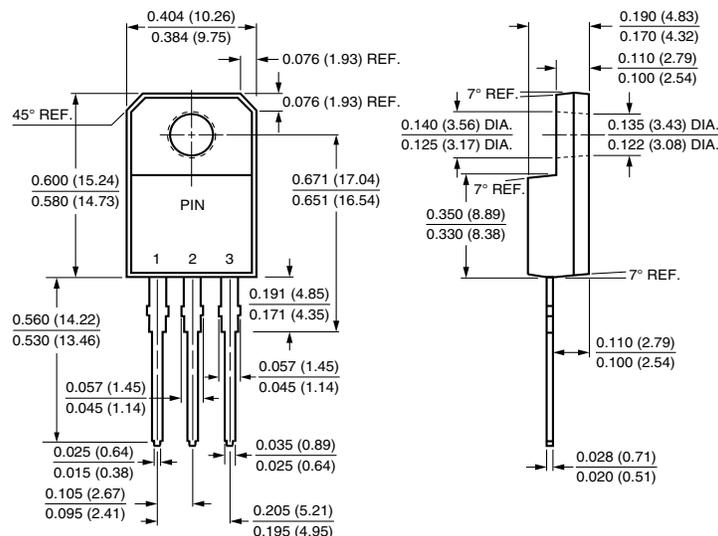


Fig. 6 - Typical Junction Capacitance

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**ITO-220AB**





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